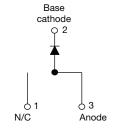


High Performance Schottky Rectifier, 20 A



TO-263AB (D²PAK)



DDODUOT CUMMADY

PRODUCT SUMMARY	
I _{F(AV)}	20 A
V _R	15 V
V _F at I _F	0.33 V
I _{RM} max.	600 mA at 100 °C
T _J max.	125 °C
E _{AS}	10 mJ
Package	TO-263AB (D ² PAK)
Diode variation	Single die

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- · Center tap module
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	20	А							
V _{RRM}		15	V							
I _{FSM}	t _p = 5 μs sine	700	А							
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V							
T _J	Range	-55 to +125	°C							

VOLTAGE RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VS-STPS20L15GPbF	UNITS						
Maximum DC reverse voltage	V _R	T _{.1} = 100 °C	15	V						
Maximum working peak reverse voltage	V_{RWM}	1J = 100 C	15	V						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C,	20						
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	700	Α				
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	330					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 6 \text{mH}$		10	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu	2	А					





ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		19 A	T _{.1} = 25 °C	-	0.41	V			
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j = 25 C	-	0.52				
See fig. 1	V FM (*)	19 A	T _J = 125 °C	0.25	0.33				
		40 A	1) = 123 0	0.37	0.50				
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	10	mA			
See fig. 2		T _J = 100 °C	V _R = nateu V _R	-	600	IIIA			
Threshold voltage	V _{F (TO)}	T - T movimum	0.182		V				
Forward slope resistance	r _t	$T_J = T_J$ maximum	7.6		mW				
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range	-	2000	pF				
Typical series inductance	L _S	Measured lead to lead 5 n	8	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperat	ure range	TJ		-55 to +125	°C				
Maximum storage temperat	ure range	T _{Stg}		-55 to +150	- U				
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W				
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation (for D ² PAK)	40					
Approximate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm				
woulding torque	maximum		NOTI-TUDITCATED THEADS	12 (10)	(lbf · in)				
Marking device			Case style D ² PAK	STPS20L15G					

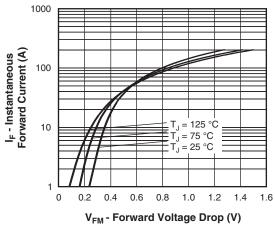


Fig. 1 - Maximum Forward Voltage Drop Characteristics

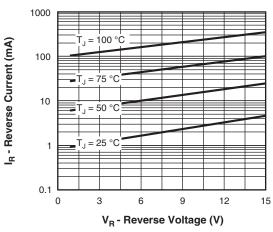


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

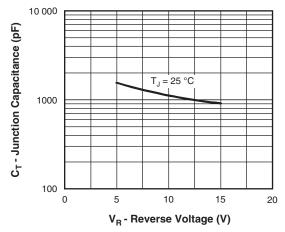


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

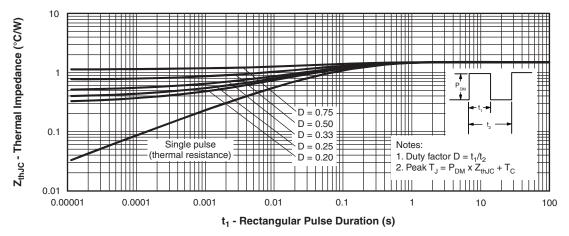


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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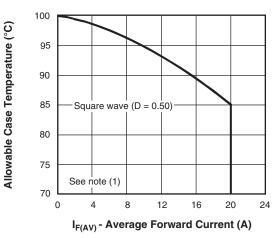


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

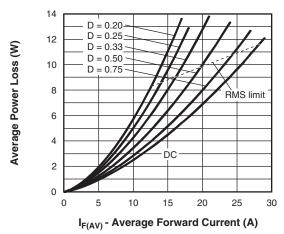


Fig. 6 - Forward Power Loss Characteristics

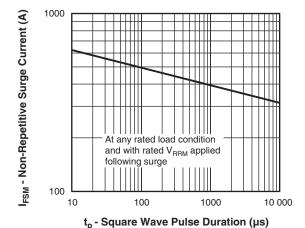


Fig. 7 - Maximum Non-Repetitive Surge Current

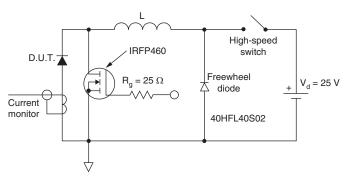


Fig. 8 - Unclamped Inductive Test Circuit

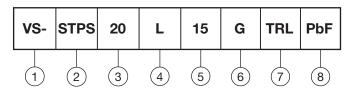
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Essential part number

Current rating (20 = 20 A)

4 - Low voltage

5 - Voltage rating (15 = 15 V)

6 - G = D²PAK package

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

PbF = lead (Pb)-free (for D²PAK tube)

• P = lead (Pb)-free (for D²PAK TRR and TRL)

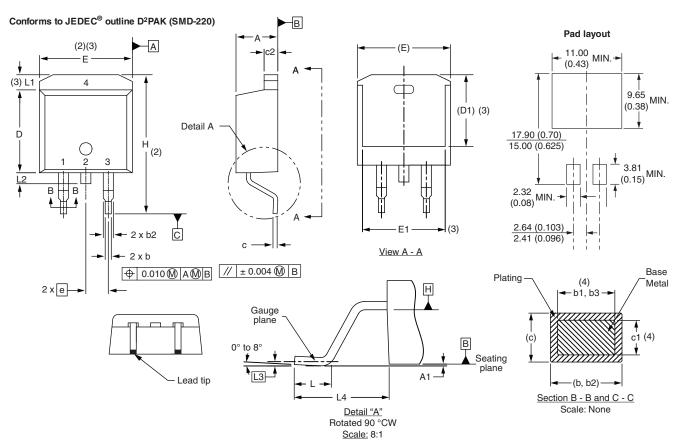
ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-STPS20L15GPbF	50	1000	Antistatic plastic tubes							
VS-STPS20L15GTRLP	800	800	13" diameter reel							
VS-STPS20L15GTRRP	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054						
Packaging information	www.vishay.com/doc?95032						



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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